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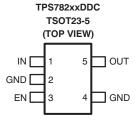
500nA, I_Q 150mA, Ultra-Low Quiescent Current Low-Dropout Linear Regulator

FEATURES

- Low I_Q: 500nA
- 150mA, Low-Dropout Regulator
- Low-Dropout at +25°C, 130mV at 150mA
- Low-Dropout at +85°C, 175mV at 150mA
- 3% Accuracy Over Load/Line/Temperature
- Available in Fixed Voltage Options (2.5V, 2.7V, and 2.8V) Using Innovative Factory EEPROM Programming
- Stable with a 1.0μF Ceramic Capacitor
- Thermal Shutdown and Overcurrent Protection
- CMOS Logic Level-Compatible Enable Pin
- Available in DDC (TSOT23-5) or DRV (2mm x 2mm SON-6) Packages

APPLICATIONS

- TI MSP430 Attach Applications
- · Power Rails with Programming Mode
- Wireless Handsets, Smartphones, PDAs, MP3
 Players, and Other Battery-Operated Handheld
 Products



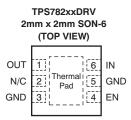
DESCRIPTION

The TPS782 family of low-dropout regulators (LDOs) offers the benefits of ultra-low power ($I_Q = 1\mu A$), and miniaturized packaging (2×2 SON).

This LDO is designed specifically for battery-powered applications where ultra-low quiescent current is a critical parameter. The TPS782, with ultra-low I_Q (1 μ A), is ideal for microprocessors, memory cards, and smoke detectors.

The ultra-low power and miniaturized packaging allow designers to customize power consumption for specific applications. Consult with your local factory representative for exact voltage options and ordering information; minimum order quantities may apply.

The TPS782 family is designed to be compatible with the TI MSP430 and other similar products. The enable pin (EN) is compatible with standard CMOS logic. This LDO is stable with any output capacitor greater than $1.0\mu F$. Therefore, this device requires minimal board space because of miniaturized packaging and a potentially small output capacitor. The TPS782 series also features thermal shutdown and current limit to protect the device during fault conditions. All packages have an operating temperature range of $T_{\rm J}=-40\,^{\circ}{\rm C}$ to +125 $^{\circ}{\rm C}$. For high-performance applications that require a dual-level voltage option, consider the TPS780 series, with an $I_{\rm Q}$ of 500nA and dynamic voltage scaling.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ORDERING INFORMATION(1) (2)

PRODUCT	V _{out}
•••	XX is the nominal output voltage YYY is the package designator. Z is the tape and reel quantity (R = 3000, T = 250).

- (1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or visit the device product folder at www.ti.com.
- (2) Additional output voltage combinations are available on a quick-turn basis using innovative, factory EEPROM programming. Minimum-order quantities apply; contact your sales representative for details and availability

ABSOLUTE MAXIMUM RATINGS(1)

At T₁ = -40°C to +125°C, unless otherwise noted. All voltages are with respect to GND.

PARAMETER		TPS782xx	UNIT			
Input voltage ran	ge, V _{IN}	-0.3 to +6.0	V			
Enable		−0.3 to V _{IN} + 0.3V	V			
Output voltage ra	ange, V _{OUT}	-0.3 to V _{IN} + 0.3V V Internally limited				
Maximum output	current, I _{OUT}	Internally limited				
Output short-circ	uit duration	Indefinite				
Total continuous	power dissipation, P _{DISS}	See the Dissipation Ratin	ite			
CCD ration	Human body model (HBM)	2	kV			
ESD rating	Charged device model (CDM)	-0.3 to V _{IN} + 0.3V Internally limited Indefinite See the Dissipation Ratings tab	V			
Operating junction	on temperature range, T _J	-40 to +125	°C			
Storage tempera	ture range, T _{STG}	-55 to +150	°C			

⁽¹⁾ Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

DISSIPATION RATINGS

BOARD	PACKAGE	R _θ JC	$R_{ heta JA}$	DERATING FACTOR ABOVE T _A = +25°C	T _A < +25°C	T _A = +70°C	T _A = +85°C
High-K ⁽¹⁾	DRV	20°C/W	65°C/W	15.4mW/°C	1540mW	845mW	615mW
High-K ⁽¹⁾	DDC	90°C/W	200°C/W	5.0mW/°C	500mW	275mW	200mW

(1) The JEDEC high-K (2s2p) board used to derive this data was a 3-inch x 3-inch, multilayer board with 1-ounce internal power and ground planes and 2-ounce copper traces on top and bottom of the board.

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ELECTRICAL CHARACTERISTICS

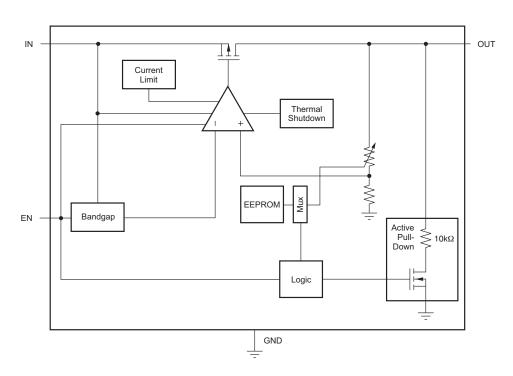
Over operating temperature range ($T_J = -40^{\circ}C$ to +125°C), $V_{IN} = V_{OUT(NOM)} + 0.5V$ or 2.2V, whichever is greater; $I_{OUT} = 100\mu A$, $V_{EN} = V_{IN}$, $C_{OUT} = 1.0\mu F$, fixed V_{OUT} test conditions, unless otherwise noted. Typical values at $T_J = +25^{\circ}C$.

					TF	PS782xx				
	PARAMETER		TEST CO	NDITIONS	MIN	TYP	MAX	UNIT		
V _{IN}	Input voltage range				2.2		5.5	V		
		Nominal	T _J = +25°C		-2	±1	+2	%		
V_{OUT}	DC output accuracy	Over V _{IN} , I _{OUT} , temperature	$V_{OUT} + 0.5V \le V_{IN} \le 0$ $0mA \le I_{OUT} \le 150mA$		-3.0	±2.0	+3.0	%		
$\Delta V_{OUT}/\Delta V_{IN}$	Line regulation		$V_{OUT(NOM)} + 0.5V \le V$		±1.0		%			
$\Delta V_{OUT}/\Delta I_{OUT}$	Load regulation		0mA ≤ I _{OUT} ≤ 150mA			±2.0		%		
V _{DO}	Dropout voltage (1)		V _{IN} = 95% V _{OUT(NOM)}	, I _{OUT} = 150mA		130	250	mV		
V _N	Output poice voltage		BW = 100Hz to 100k V _{OUT} = 1.2V, I _{OUT} = 2			86		μV_{RMS}		
I _{CL}	Output current limit		$V_{OUT} = 0.90 \times V_{OUT(1)}$	150	230	400	mA			
			I _{OUT} = 0mA		0.42	1.3	μА			
I_{GND}	Ground pin current		I _{OUT} = 150mA			8		μΑ		
I _{SHDN}	Shutdown current (I _{GI}	_{ND})	$V_{EN} \le 0.4V$, $2.2V \le V$ $T_{J} = -40^{\circ}C$ to $+100^{\circ}C$	$_{N} \le 0.4 \text{V}, 2.2 \text{V} \le \text{V}_{ N} < 5.5 \text{V},$ = -40°C to +100°C		18	130	nA		
I _{EN}	EN pin current		V _{EN} = 5.5V				40	nA		
			$V_{IN} = 4.3V$,	f = 10Hz		40		dB		
PSRR	Power-supply rejection	n ratio	$V_{OUT} = 3.3V$,	f = 100Hz		20		dB		
			$I_{OUT} = 150mA$	f = 1kHz		15		dB		
t _{STR}	Startup time ⁽²⁾		$C_{OUT} = 1.0 \mu F, V_{OUT} = V_{OUT} = 90\% V_{OUT(NO)}$			500		μS		
^t SHDN	Shutdown time ⁽³⁾	Shutdown time ⁽³⁾		$I_{OUT} = 150$ mA, $C_{OUT} = 1.0 \mu$ F, $V_{OUT} = 2.8 V$, $V_{OUT} = 90\% \ V_{OUT(NOM)}$ to $V_{OUT} = 10\%$		$I_{OUT} = 150$ mA, $C_{OUT} = 1.0$ μ F, $V_{OUT} = 2.8$ V, $V_{OUT} = 90$ % $V_{OUT(NOM)}$ to $V_{OUT} = 10$ % $V_{OUT(NOM)}$		500 ⁽⁴⁾		μS
_	The read objected assets		Shutdown, temperatu		+160		°C			
T_{SD}	Thermal shutdown te	прегатиге	Reset, temperature of	lecreasing		+140		°C		
TJ	Operating junction ter	mperature			-40		+125	°C		

 V_{DO} is not measured for devices with $V_{OUT(NOM)} \leq 2.3 V$ because minimum $V_{IN} = 2.2 V$. Time from $V_{EN} = 1.2 V$ to $V_{OUT} = 90\%$ ($V_{OUT(NOM)}$). Time from $V_{EN} = 0.4 V$ to $V_{OUT} = 10\%$ ($V_{OUT(NOM)}$). See <code>Shutdown</code> in the <code>Application Information</code> section for more details.



FUNCTIONAL BLOCK DIAGRAM



PIN CONFIGURATIONS



- (1) All ground pins must be connected to ground for proper operation.
- (2) It is recommended that the thermal pad be grounded.

Table 1. PIN DESCRIPTIONS

	PIN							
NAME	DRV	DDC	DESCRIPTION					
OUT	1	5	Regulated output voltage pin. A small (1µF) ceramic capacitor is needed from this pin to ground to assure stability. See the <i>Input and Output Capacitor Requirements</i> in the Application Information section for more details.					
N/C	2	_	Not connected.					
EN	4	3	Driving the enable pin (EN) over 1.2V turns ON the regulator. Driving this pin below 0.4V puts the regulator into shutdown mode, reducing operating current to 18nA typical.					
GND	3, 5	2, 4	ALL ground pins must be tied to ground for proper operation.					
IN	6	1	Input pin. A small capacitor is needed from this pin to ground to assure stability. Typical input capacitor = $1.0\mu F$. Both input and output capacitor grounds should be tied back to the IC ground with no significant impedance between them.					
Thermal pad	Thermal pad	_	It is recommended that the thermal pad on the SON-6 package be connected to ground.					



TYPICAL CHARACTERISTICS

Over the operating temperature range of $T_J = -40^{\circ}C$ to +125°C, $V_{IN} = V_{OUT(TYP)} + 0.5V$ or 2.2V, whichever is greater; $I_{OUT} = 100\mu A$, $V_{EN} = V_{IN}$, $C_{OUT} = 1\mu F$, and $C_{IN} = 1\mu F$, unless otherwise noted.

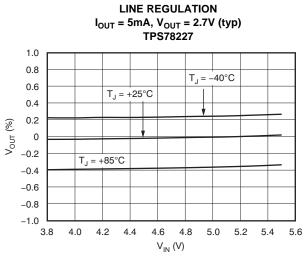


Figure 1.

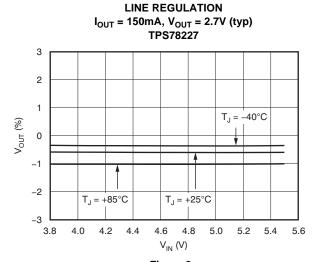


Figure 2.



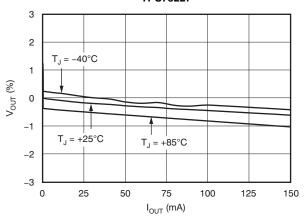


Figure 3.

DROPOUT VOLTAGE vs OUTPUT CURRENT $V_{OUT} = 2.7V$ (typ), $V_{IN} = 0.95 \times V_{OUT}$ (typ)

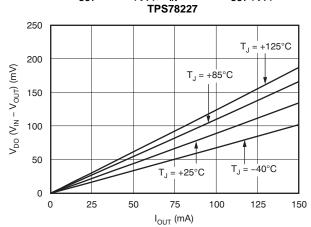


Figure 4.



Over the operating temperature range of $T_J = -40^{\circ}C$ to $+125^{\circ}C$, $V_{IN} = V_{OUT(TYP)} + 0.5V$ or 2.2V, whichever is greater; $I_{OUT} = 100\mu A$, $V_{EN} = V_{IN}$, $C_{OUT} = 1\mu F$, and $C_{IN} = 1\mu F$, unless otherwise noted.

DROPOUT VOLTAGE vs JUNCTION TEMPERATURE V_{OUT} = 2.7V (typ), V_{IN} = 0.95 × V_{OUT} (typ)

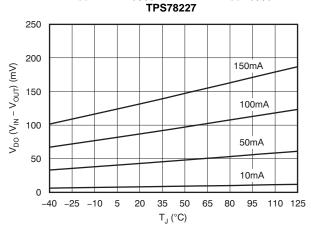


Figure 5.

GROUND PIN CURRENT vs INPUT VOLTAGE $I_{OUT} = 0 mA, \ V_{OUT} = 3.3 V$ TPS78233

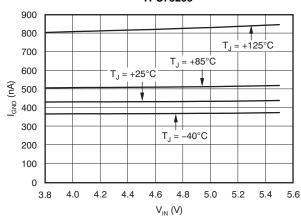


Figure 6.

GROUND PIN CURRENT vs INPUT VOLTAGE $I_{OUT} = 50$ mA, $V_{OUT} = 2.7V$ TPS78227

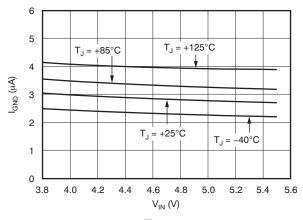


Figure 7.

GROUND PIN CURRENT vs INPUT VOLTAGE $I_{OUT} = 150 \text{mA}, V_{OUT} = 2.7V$ TPS78227

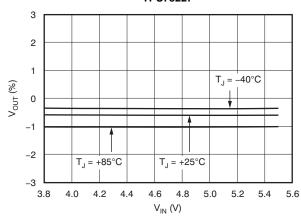


Figure 8.



Over the operating temperature range of $T_J=-40^{\circ}C$ to +125°C, $V_{IN}=V_{OUT(TYP)}+0.5V$ or 2.2V, whichever is greater; $I_{OUT}=100\mu A$, $V_{EN}=V_{IN}$, $C_{OUT}=1\mu F$, and $C_{IN}=1\mu F$, unless otherwise noted.

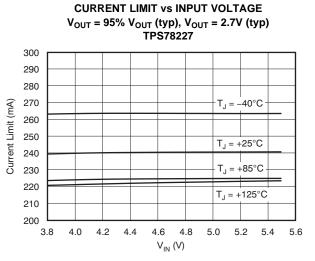


Figure 9.

$I_{OUT} = 100 \mu A, V_{OUT} = 2.7 V$ **TPS78227** 2.0 1.8 1.6 1.4 $T_J = -40^{\circ}C$ 1.2 I_{EN} (nA) T = +25°C 1.0 $T_{.1} = +85^{\circ}C$ 0.8 0.6 0.4 0.2 0 3.8 4.0 4.2 4.4 4.6 4.8 5.0 5.2 5.4 5.6

ENABLE PIN CURRENT vs INPUT VOLTAGE

V_{IN} (V) Figure 10.

ENABLE PIN HYSTERESIS vs JUNCTION TEMPERATURE $I_{OUT} = 1 \text{mA}$, TPS78227

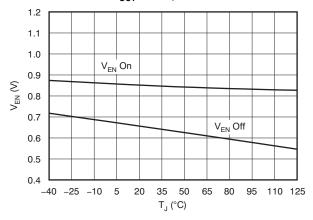


Figure 11.

$\%\Delta V_{OUT}$ vs JUNCTION TEMPERATURE $V_{IN}=3.3V,\,V_{OUT}=2.7V$ (typ) TPS78227

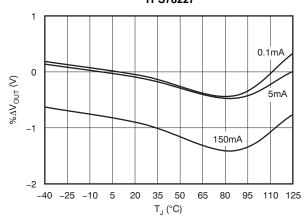


Figure 12.



Over the operating temperature range of $T_J = -40^{\circ}C$ to $+125^{\circ}C$, $V_{IN} = V_{OUT(TYP)} + 0.5V$ or 2.2V, whichever is greater; $I_{OUT} = 100\mu A$, $V_{EN} = V_{IN}$, $C_{OUT} = 1\mu F$, and $C_{IN} = 1\mu F$, unless otherwise noted.

$\%\Delta V_{OUT}$ vs JUNCTION TEMPERATURE $V_{IN} = 3.7V, V_{OUT} = 2.7V \text{ (typ)}$ **TPS78227** 3 2 $%\Delta V_{OUT}$ (V) 0.1mA 0 5mA -1 150mA -2 -3 -40 -25 -10 5 20 35 50 65 80 95 110 125 T_J (°C)

Figure 13.

OUTPUT SPECTRAL NOISE DENSITY vs FREQUENCY $C_{IN} = 1 \mu F, \ C_{OUT} = 2.2 \mu F, \ V_{IN} = 3.2 V$ TPS78227

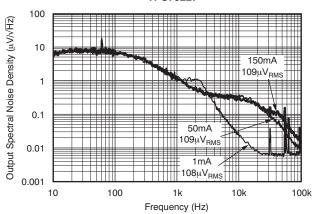


Figure 14.

RIPPLE REJECTION vs FREQUENCY $V_{IN} = 4.2V, \, V_{OUT} = 2.7V, \, C_{OUT} = 2.2 \mu F$ TPS78227

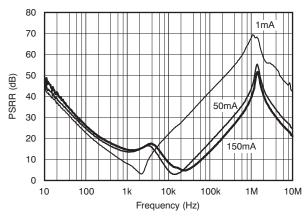


Figure 15.

INPUT VOLTAGE RAMP vs OUTPUT VOLTAGE TPS78233

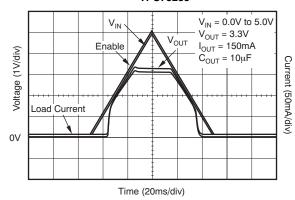


Figure 16.



Over the operating temperature range of $T_J=-40^{\circ}C$ to +125°C, $V_{IN}=V_{OUT(TYP)}+0.5V$ or 2.2V, whichever is greater; $I_{OUT}=100\mu A$, $V_{EN}=V_{IN}$, $C_{OUT}=1\mu F$, and $C_{IN}=1\mu F$, unless otherwise noted.

OUTPUT VOLTAGE vs ENABLE (SLOW RAMP) TPS78233

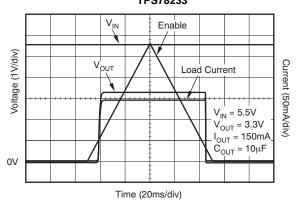


Figure 17.

INPUT VOLTAGE vs DELAY TO OUTPUT TPS78222

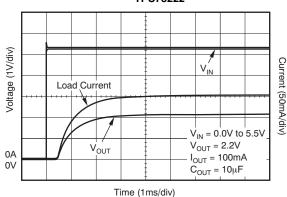


Figure 18.

LOAD TRANSIENT RESPONSE TPS78233

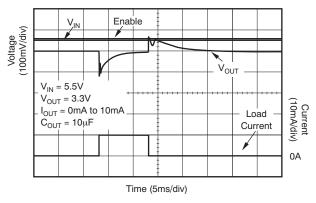


Figure 19.

ENABLE PIN vs OUTPUT VOLTAGE RESPONSE AND OUTPUT CURRENT TPS78233

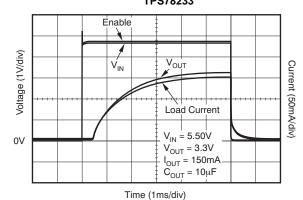
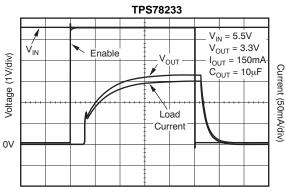


Figure 20.

ENABLE PIN vs OUTPUT VOLTAGE DELAY



Time (1 ms/div)

Figure 21.



APPLICATION INFORMATION

APPLICATION EXAMPLES

The TPS782 family of LDOs is factory-programmable to have a fixed output. Note that during startup or steady-state conditions, it is important that the EN pin voltage never exceed $V_{IN} + 0.3V$.

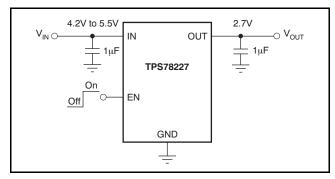


Figure 22. Typical Application Circuit

INPUT AND OUTPUT CAPACITOR REQUIREMENTS

Although an input capacitor is not required for stability, it is good analog design practice to connect a 0.1μF to 1.0μF low equivalent series resistance (ESR) capacitor across the input supply near the regulator. This capacitor counteracts reactive input sources and improves transient response, noise rejection, and ripple rejection. A higher-value capacitor may be necessary if large, fast rise-time load transients are anticipated, or if the device is not located near the power source. If source impedance is not sufficiently low, a 0.1 µF input capacitor may be necessary to ensure stability.

The TPS782 series are designed to be stable with standard ceramic capacitors with values of 1.0µF or larger at the output. X5R- and X7R-type capacitors are best because they have minimal variation in value and ESR over temperature. Maximum ESR should be less than 1.0Ω . With tolerance and dc bias effects, the minimum capacitance to ensure stability is 1µF.

BOARD LAYOUT RECOMMENDATIONS TO IMPROVE PSRR AND NOISE PERFORMANCE

To improve ac performance (such as PSRR, output noise, and transient response), it is recommended that the printed circuit board (PCB) be designed with separate ground planes for V_{IN} and V_{OUT}, with each ground plane connected only at the GND pin of the device. In addition, the ground connection for the output capacitor should connect directly to the GND pin of the device. High ESR capacitors may degrade PSRR.

INTERNAL CURRENT LIMIT

The TPS782 is internally current-limited to protect the regulator during fault conditions. During current limit. the output sources a fixed amount of current that is largely independent of output voltage. For reliable operation, the device should not be operated in a current limit state for extended periods of time.

The PMOS pass element in the TPS782 series has a built-in body diode that conducts current when the voltage at OUT exceeds the voltage at IN. This current is not limited, so if extended reverse voltage operation is anticipated, external limiting to 5% of rated output current may be appropriate.



SHUTDOWN

The enable pin (EN) is active high and is compatible with standard and low-voltage CMOS levels. When shutdown capability is not required, EN should be connected to the IN pin, as shown in Figure 23. The TPS782 series, with internal active output pull-down circuitry, discharges the output to within 5% V_{OUT} with a time (t) shown in Equation 1:

$$t = 3 \left[\frac{10k\Omega \times R_L}{10k\Omega + R_L} \right] \times C_{OUT}$$
 (1)

Where:

 R_L = output load resistance C_{OUT} = output capacitance

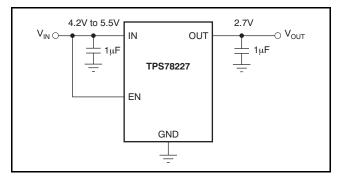


Figure 23. Circuit Showing EN Tied High when Shutdown Capability is Not Required

DROPOUT VOLTAGE

The TPS782 series use a PMOS pass transistor to achieve low dropout. When $(V_{IN} - V_{OUT})$ is less than the dropout voltage (V_{DO}) , the PMOS pass device is the linear region of operation and the input-to-output resistance is the $R_{DS(ON)}$ of the PMOS pass element. V_{DO} approximately scales with output current because the PMOS device behaves like a resistor in dropout. As with any linear regulator, PSRR and transient response are degraded as $(V_{IN} - V_{OUT})$ approaches dropout. This effect is shown in the Typical Characteristics section. Refer to application report SLVA207, *Understanding LDO Dropout*, available for download from www.ti.com.

TRANSIENT RESPONSE

As with any regulator, increasing the size of the output capacitor reduces over/undershoot magnitude but increases duration of the transient response. For more information, see Figure 19.

ACTIVE VOUT PULL-DOWN

In the TPS782 series, the active pull-down discharges V_{OUT} when the device is off. However, the input voltage must be greater than 2.2V for the active pull-down to work.

MINIMUM LOAD

The TPS782 series are stable with no output load. Traditional PMOS LDO regulators suffer from lower loop gain at very light output loads. The TPS782 employs an innovative, low-current circuit under very light or no-load conditions, resulting in improved output voltage regulation performance down to zero output current. See Figure 19 for the load transient response.



THERMAL INFORMATION

THERMAL PROTECTION

Thermal protection disables the device output when the junction temperature rises to approximately +160°C, allowing the device to cool. Once the junction temperature cools to approximately +140°C, the output circuitry is enabled. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off again. This cycling limits the dissipation of the regulator, protecting it from damage as a result of overheating.

Any tendency to activate the thermal protection circuit indicates excessive power dissipation or an inadequate heatsink. For reliable operation, junction temperature should be limited to +125°C maximum. To estimate the margin of safety in a complete design heatsink), increase (including the temperature until the thermal protection is triggered; use worst-case loads and signal conditions. For good reliability, thermal protection should trigger at least +35°C above the maximum expected ambient condition of your particular application. This configuration produces a worst-case junction temperature of +125°C at the highest expected ambient temperature and worst-case load.

The internal protection circuitry of the TPS782 series has been designed to protect against overload conditions. However, it is not intended to replace proper heatsinking. Continuously running the TPS782 series into thermal shutdown degrades device reliability.

POWER DISSIPATION

The ability to remove heat from the die is different for package type, presenting considerations in the PCB layout. The PCB area around the device that is free of other components moves the heat from the device to the ambient air. Performance data for JEDEC low- and high-K boards are given in the Dissipation Ratings table. Using heavier copper increases the effectiveness in removing heat from the device. The addition of plated through-holes to heat-dissipating layers improves the heatsink effectiveness. dissipation depends on input voltage and load conditions. Power dissipation (PD) is equal to the product of the output current times the voltage drop across the output pass element (V_{IN} to V_{OLIT}), as shown in Equation 2:

$$P_{D} = (V_{IN} - V_{OUT}) \times I_{OUT}$$
 (2)

PACKAGE MOUNTING

Solder pad footprint recommendations for the TPS782 series are available from the Texas Instruments web site at www.ti.com through the TPS782 series product folders.

www.ti.com

REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Ci	nanges from Revision A (September, 2008) to Revision B	Page
•	Updated title of data sheet	1
•	Changed first bullet of Features list	1
•	Changed ground pin current, I _{OUT} = 0mA typical specification from 1.0μA to 0.42μA	3
•	Added Figure 6	6



www.ti.com 3-Dec-2009

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TPS78223DDCR	ACTIVE	SOT	DDC	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS78223DDCT	ACTIVE	SOT	DDC	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS78225DDCR	ACTIVE	SOT	DDC	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS78225DDCRG4	ACTIVE	SOT	DDC	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS78225DDCT	ACTIVE	SOT	DDC	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS78225DDCTG4	ACTIVE	SOT	DDC	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS78225DRVR	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS78225DRVRG4	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS78225DRVT	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS78225DRVTG4	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)		Level-1-260C-UNLIM
TPS78227DDCR	ACTIVE	SOT	DDC	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS78227DDCRG4	ACTIVE	SOT	DDC	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS78227DDCT	ACTIVE	SOT	DDC	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS78227DDCTG4	ACTIVE	SOT	DDC	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS78227DRVR	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS78227DRVRG4	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS78227DRVT	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS78227DRVTG4	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS78228DDCR	ACTIVE	SOT	DDC	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS78228DDCRG4	ACTIVE	SOT	DDC	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS78228DDCT	ACTIVE	SOT	DDC	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS78228DDCTG4	ACTIVE	SOT	DDC	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS78228DRVR	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS78228DRVRG4	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS78228DRVT	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM



PACKAGE OPTION ADDENDUM

www.ti.com 3-Dec-2009

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TPS78228DRVTG4	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS78230DDCR	ACTIVE	SOT	DDC	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS78230DDCT	ACTIVE	SOT	DDC	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS78230DRVR	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS78230DRVT	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS78233DDCR	ACTIVE	SOT	DDC	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS78233DDCT	ACTIVE	SOT	DDC	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

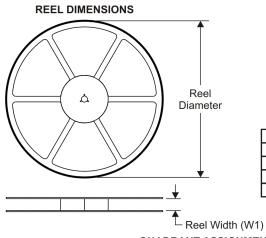
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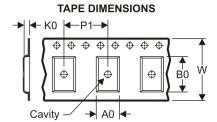
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PACKAGE MATERIALS INFORMATION

www.ti.com 18-Dec-2010

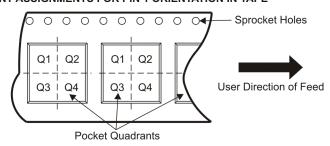
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
D1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



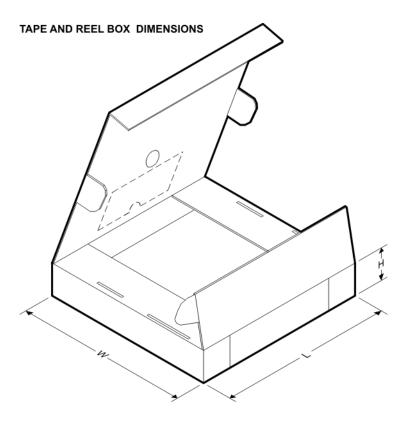
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS78223DDCR	SOT	DDC	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS78223DDCT	SOT	DDC	5	250	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS78225DDCR	SOT	DDC	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS78225DDCT	SOT	DDC	5	250	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS78225DRVR	SON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS78225DRVT	SON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS78227DDCR	SOT	DDC	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS78227DDCT	SOT	DDC	5	250	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS78227DRVR	SON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS78227DRVT	SON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS78228DDCR	SOT	DDC	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS78228DDCT	SOT	DDC	5	250	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS78228DRVR	SON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS78228DRVT	SON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS78230DDCR	SOT	DDC	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS78230DDCT	SOT	DDC	5	250	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS78230DRVR	SON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS78230DRVT	SON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2

PACKAGE MATERIALS INFORMATION

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Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS78233DDCR	SOT	DDC	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS78233DDCT	SOT	DDC	5	250	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS78223DDCR	SOT	DDC	5	3000	195.0	200.0	45.0
TPS78223DDCT	SOT	DDC	5	250	195.0	200.0	45.0
TPS78225DDCR	SOT	DDC	5	3000	195.0	200.0	45.0
TPS78225DDCT	SOT	DDC	5	250	195.0	200.0	45.0
TPS78225DRVR	SON	DRV	6	3000	203.0	203.0	35.0
TPS78225DRVT	SON	DRV	6	250	203.0	203.0	35.0
TPS78227DDCR	SOT	DDC	5	3000	195.0	200.0	45.0
TPS78227DDCT	SOT	DDC	5	250	195.0	200.0	45.0
TPS78227DRVR	SON	DRV	6	3000	203.0	203.0	35.0
TPS78227DRVT	SON	DRV	6	250	203.0	203.0	35.0
TPS78228DDCR	SOT	DDC	5	3000	195.0	200.0	45.0
TPS78228DDCT	SOT	DDC	5	250	195.0	200.0	45.0
TPS78228DRVR	SON	DRV	6	3000	203.0	203.0	35.0
TPS78228DRVT	SON	DRV	6	250	203.0	203.0	35.0
TPS78230DDCR	SOT	DDC	5	3000	195.0	200.0	45.0



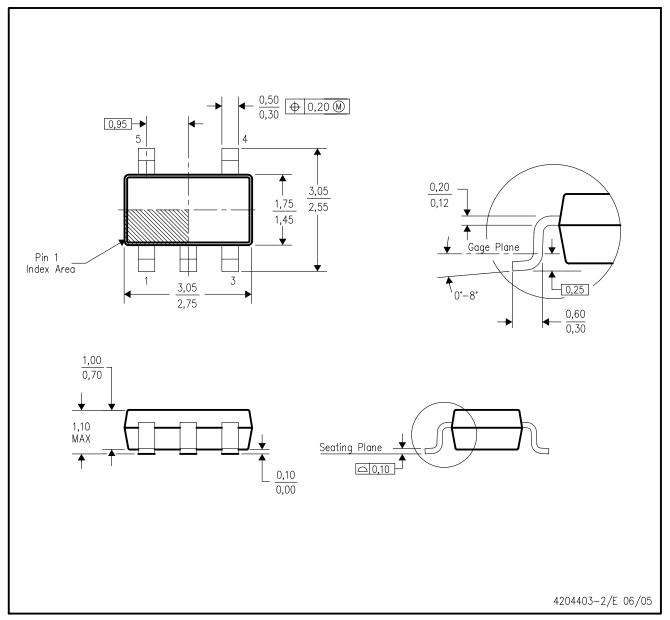
PACKAGE MATERIALS INFORMATION

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS78230DDCT	SOT	DDC	5	250	195.0	200.0	45.0
TPS78230DRVR	SON	DRV	6	3000	203.0	203.0	35.0
TPS78230DRVT	SON	DRV	6	250	203.0	203.0	35.0
TPS78233DDCR	SOT	DDC	5	3000	203.0	203.0	35.0
TPS78233DDCT	SOT	DDC	5	250	203.0	203.0	35.0

DDC (R-PDSO-G5)

PLASTIC SMALL-OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-193 variation AB (5 pin).



DRV (S-PWSON-N6)

PLASTIC SMALL OUTLINE NO-LEAD



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Small Outline No-Lead (SON) package configuration.

The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.



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